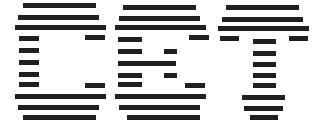


# CEPF640/CEBF640



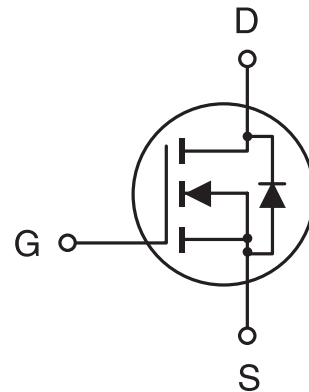
March 1998

4

## N-Channel Enhancement Mode Field Effect Transistor

### FEATURES

- 200V , 18A ,  $R_{DS(ON)}=180m\Omega$  @  $V_{GS}=10V$
- Super high dense cell design for extremely low  $R_{DS(ON)}$ .
- High power and current handling capability.
- TO-220 & TO-263 package.



### ABSOLUTE MAXIMUM RATINGS ( $T_c=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	200	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Drain Current-Continuous -Pulsed	$I_D$	18	A
	$I_{DM}$	72	A
Drain-Source Diode Forward Current	$I_S$	18	A
Maximum Power Dissipation @ $T_c=25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	125	W
		1.0	$\text{W}/^\circ\text{C}$
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to 150	$^\circ\text{C}$

### THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.0	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	62.5	$^\circ\text{C}/\text{W}$

# CEPF640/CEBF640

## ELECTRICAL CHARACTERISTICS (T<sub>c</sub>=25 °C unless otherwise noted)

4

Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>OFF CHARACTERISTICS</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	200			V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =160V, V <sub>GS</sub> =0V			25	μA
Gate-Body Leakage	I <sub>GSS</sub>	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V			±100	nA
<b>ON CHARACTERISTICS<sup>a</sup></b>						
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	2		4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =9A			180	mΩ
On-State Drain Current	I <sub>D(ON)</sub>	V <sub>GS</sub> =10V, V <sub>DS</sub> =10V	18			A
Forward Transconductance	g <sub>FS</sub>	V <sub>DS</sub> =10V, I <sub>D</sub> =9A		10.8		S
<b>DYNAMIC CHARACTERISTICS<sup>b</sup></b>						
Input Capacitance	C <sub>ISS</sub>	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V f=1.0MHz		1250	1700	pF
Output Capacitance	C <sub>OSS</sub>			188	250	pF
Reverse Transfer Capacitance	C <sub>RSS</sub>			60	80	pF
<b>SWITCHING CHARACTERISTICS<sup>b</sup></b>						
Turn-On Delay Time	t <sub>D(ON)</sub>	V <sub>DD</sub> =100V, I <sub>D</sub> =11A, V <sub>GS</sub> =10V, R <sub>GEN</sub> =9.1Ω		15	30	ns
Rise Time	t <sub>r</sub>			70	105	ns
Turn-Off Delay Time	t <sub>D(OFF)</sub>			55	85	ns
Fall Time	t <sub>f</sub>			55	70	ns
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =160V, I <sub>D</sub> =18A, V <sub>GS</sub> =10V		65	80	nC
Gate-Source Charge	Q <sub>gs</sub>			12		nC
Gate-Drain Charge	Q <sub>gd</sub>			37		nC

# CEPF640/CEBF640

## ELECTRICAL CHARACTERISTICS ( $T_c=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>DRAIN-SOURCE DIODE CHARACTERISTICS <sup>a</sup></b>						
Diode Forward Voltage	$V_{SD}$	$V_{GS} = 0\text{V}, I_s = 18\text{A}$			1.5	V

4

### Notes

- Pulse Test: Pulse Width  $\leq 300\ \mu\text{s}$ , Duty Cycle  $\leq 2\%$ .
- Guaranteed by design, not subject to production testing.

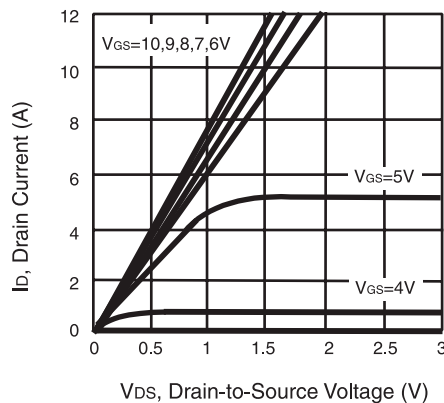


Figure 1. Output Characteristics

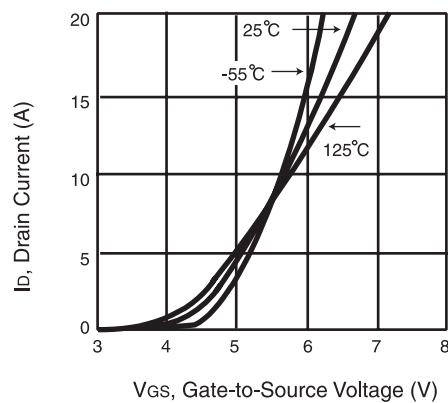


Figure 2. Transfer Characteristics

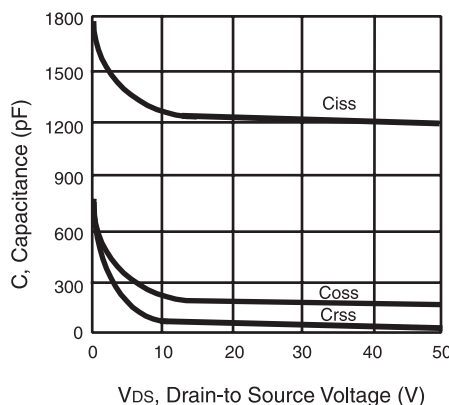


Figure 3. Capacitance

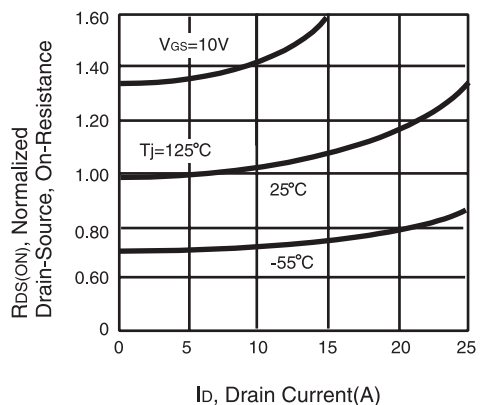
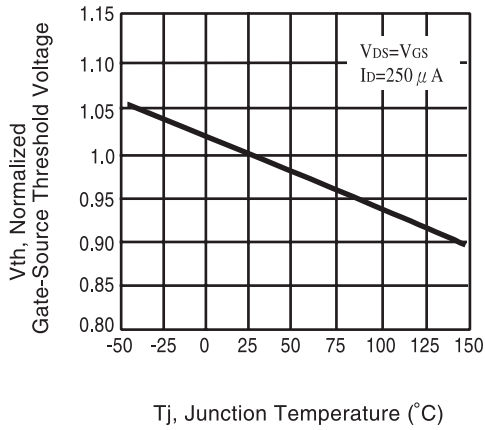


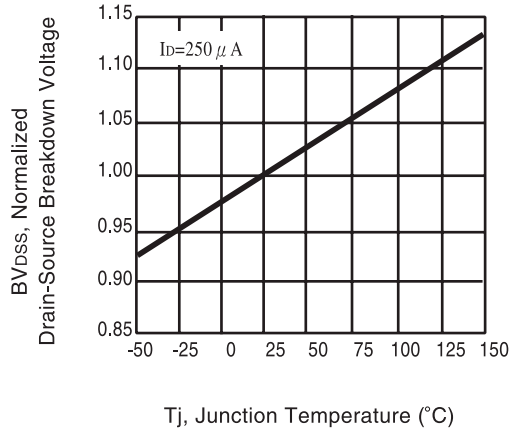
Figure 4. On-Resistance Variation with Drain Current and Temperature

# CEPF640/CEBF640

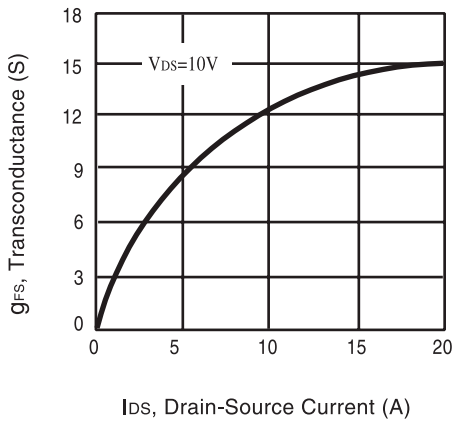
4



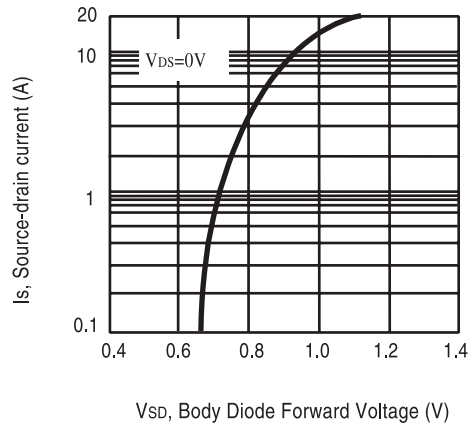
**Figure 5. Gate Threshold Variation with Temperature**



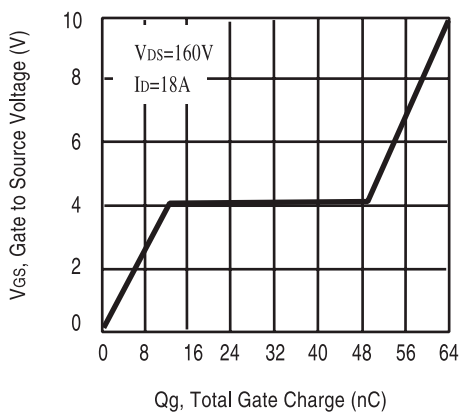
**Figure 6. Breakdown Voltage Variation with Temperature**



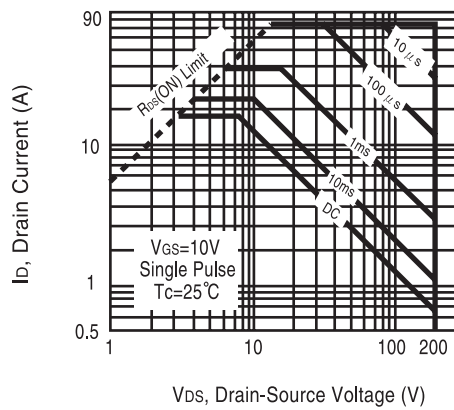
**Figure 7. Transconductance Variation with Drain Current**



**Figure 8. Body Diode Forward Voltage Variation with Source Current**



**Figure 9. Gate Charge**



**Figure 10. Maximum Safe Operating Area**

# CEPF640/CEBF640

4

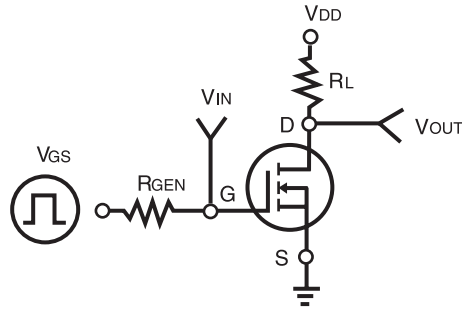


Figure 11. Switching Test Circuit

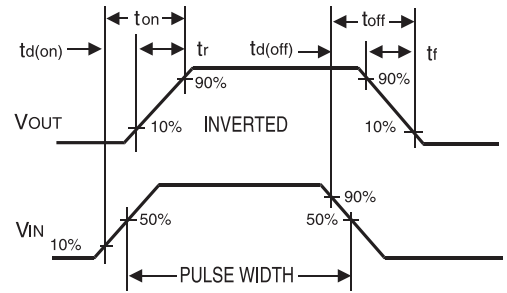


Figure 12. Switching Waveforms

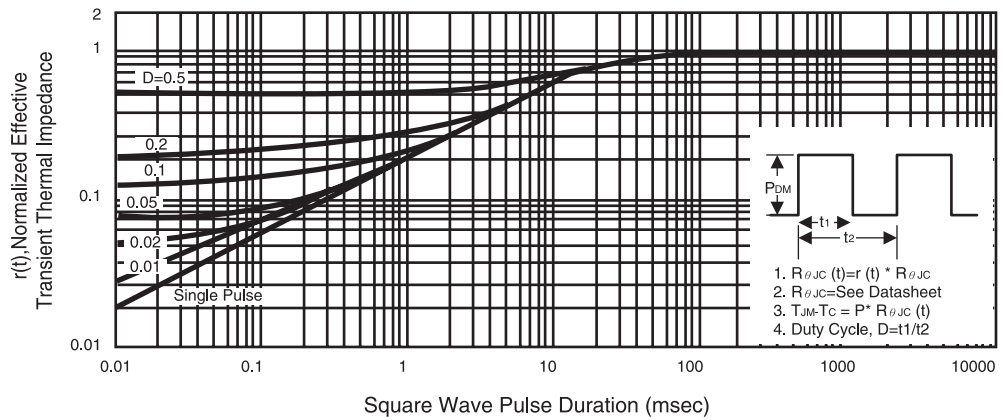


Figure 13. Normalized Thermal Transient Impedance Curve

This datasheet has been download from:

[www.datasheetcatalog.com](http://www.datasheetcatalog.com)

Datasheets for electronics components.